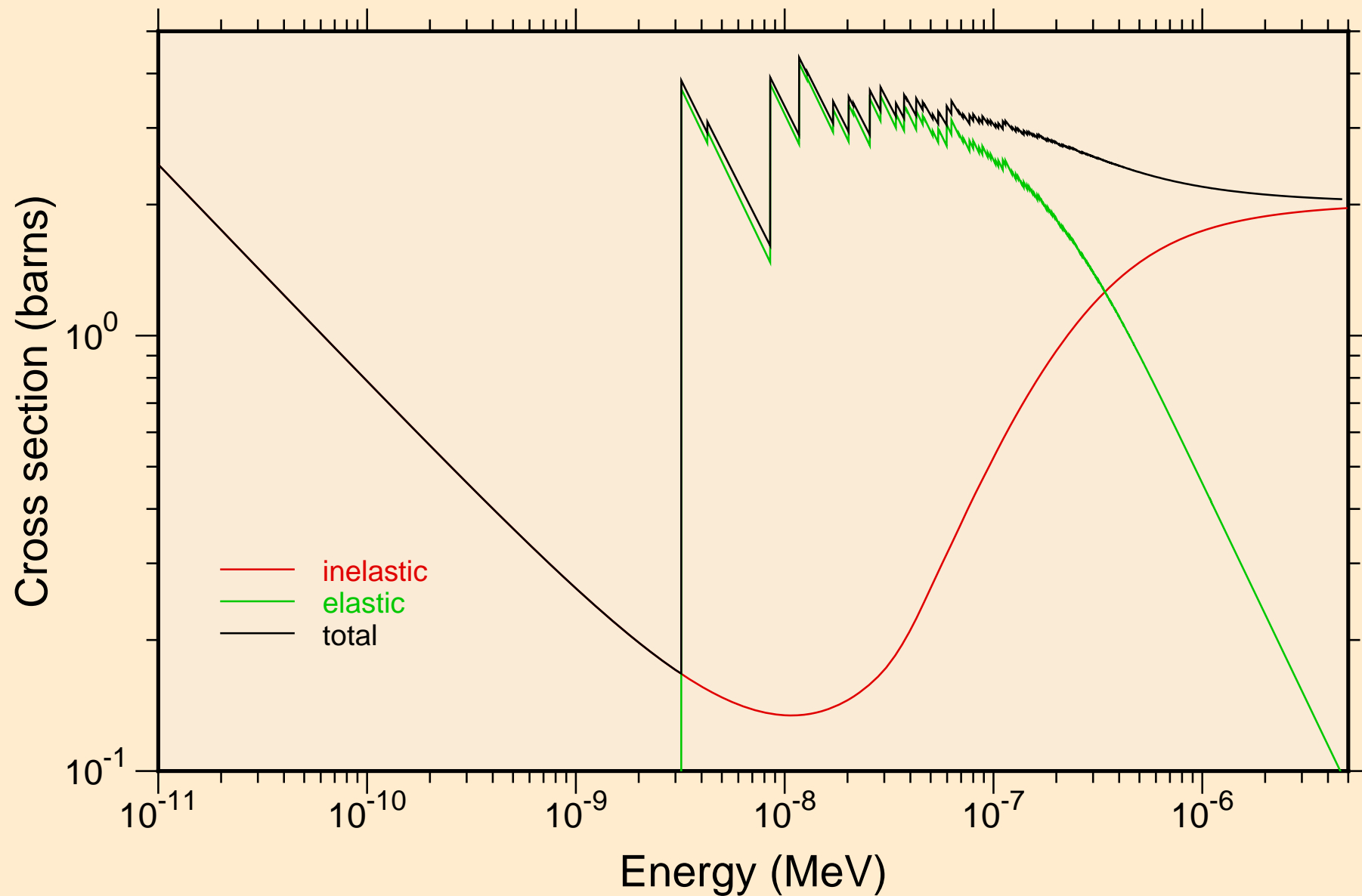
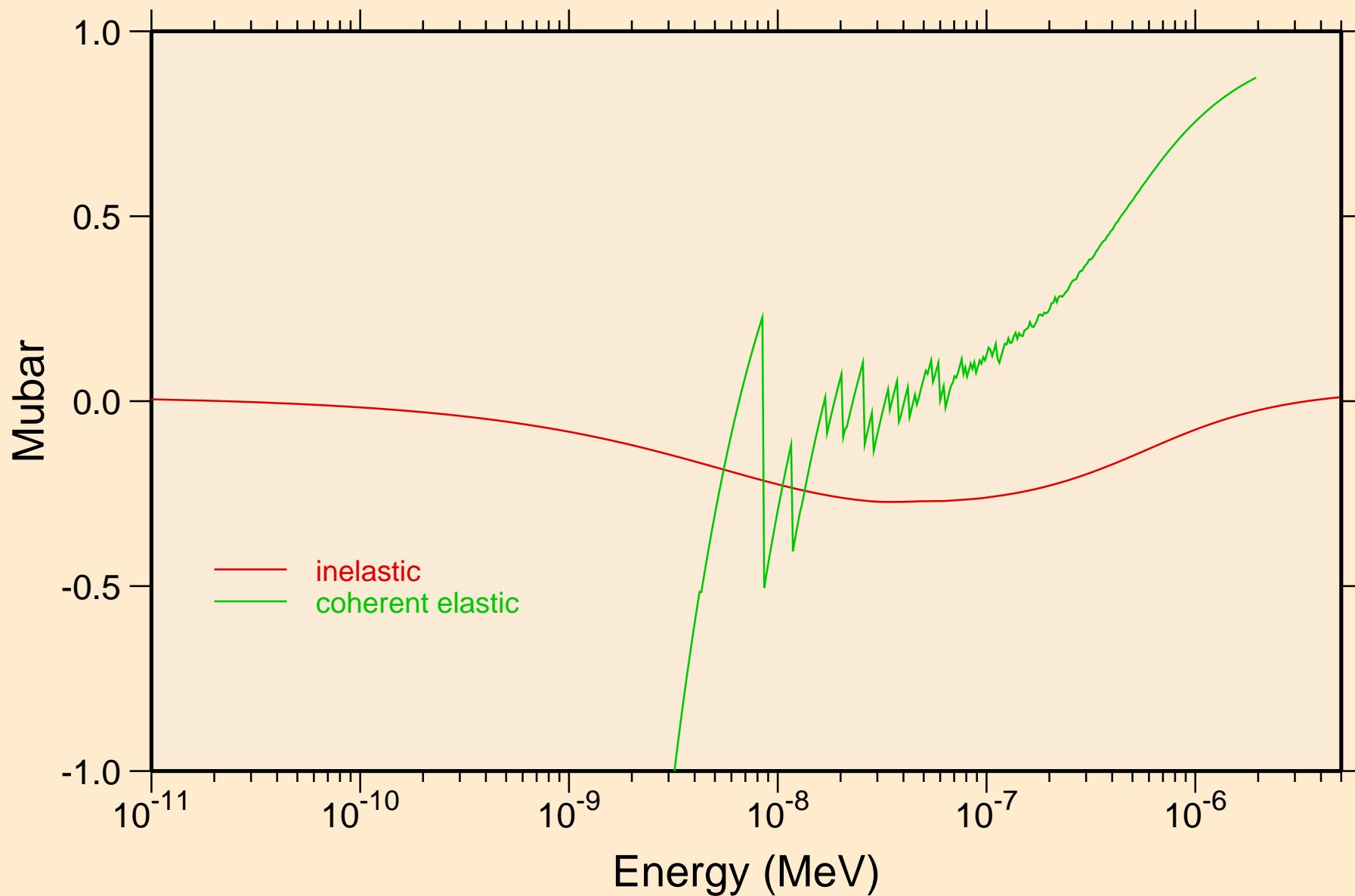


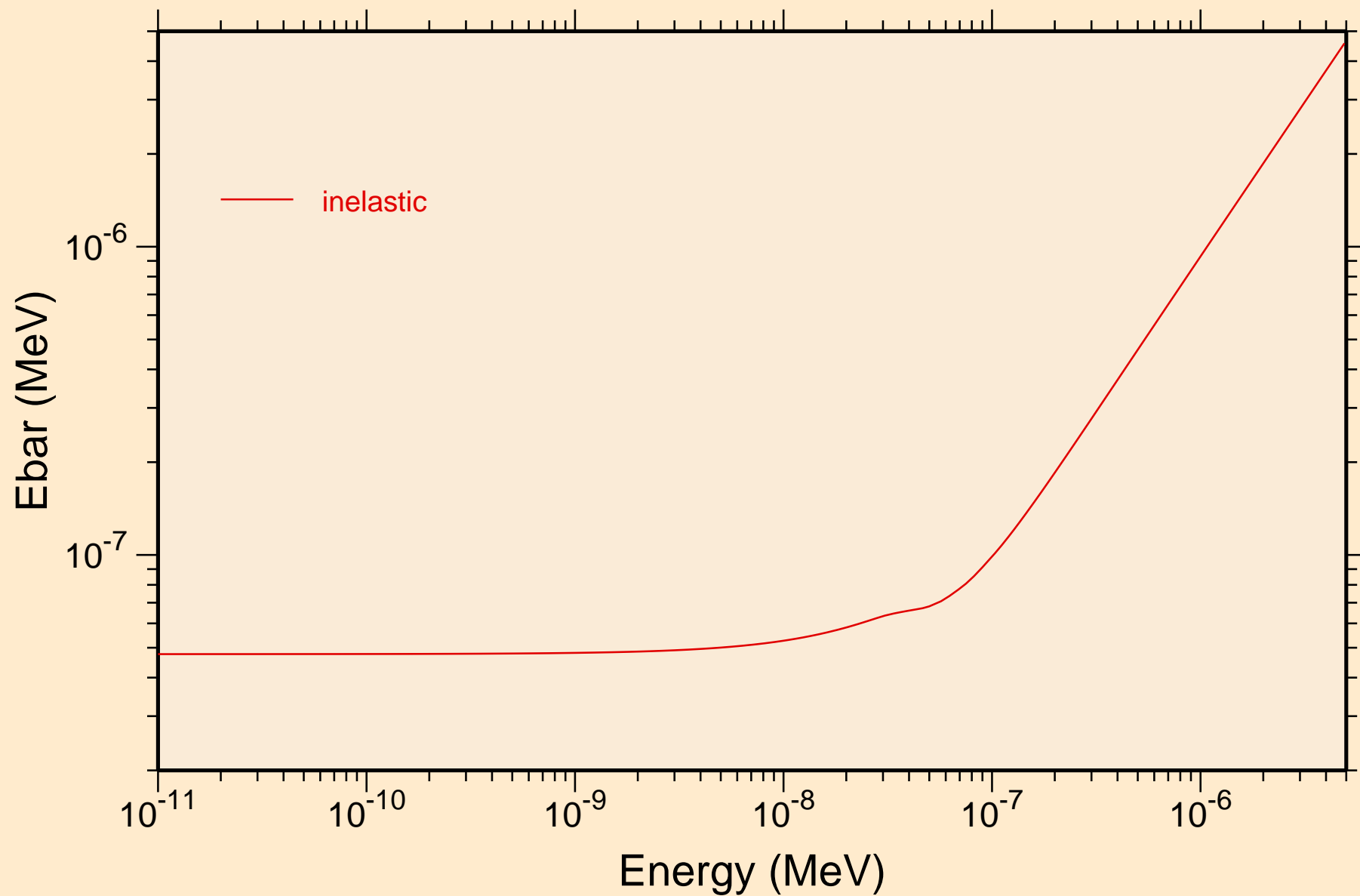
SI-SIC-BETA_SG216_BETASILICONCARBIDE @ 500.00K
Thermal cross sections



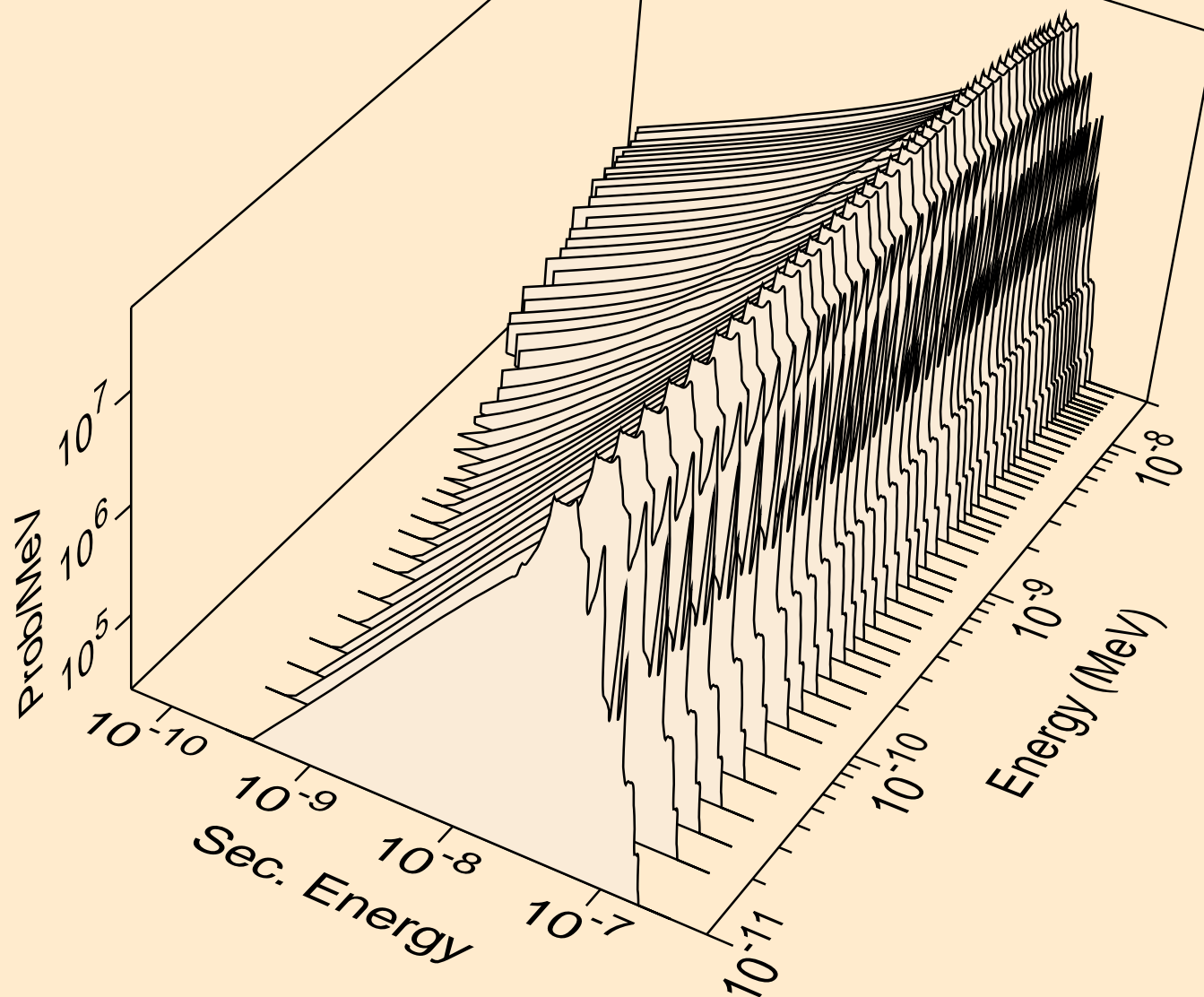
SI-SIC-BETA_SG216_BETASILICONCARBIDE @ 500.00K
Thermal mubar



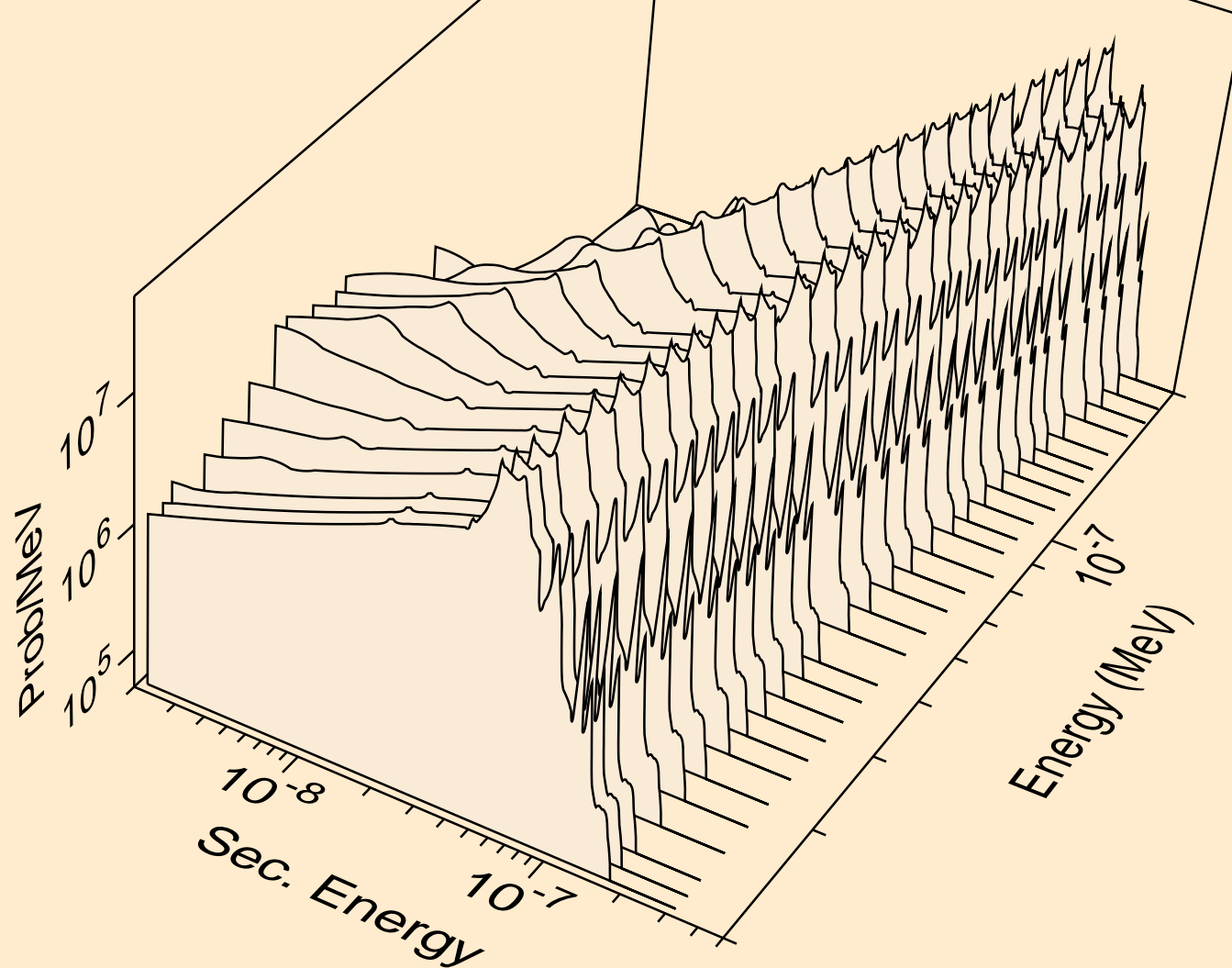
SI-SIC-BETA_SG216_BETASILICONCARBIDE @ 500.00K
Thermal ebar



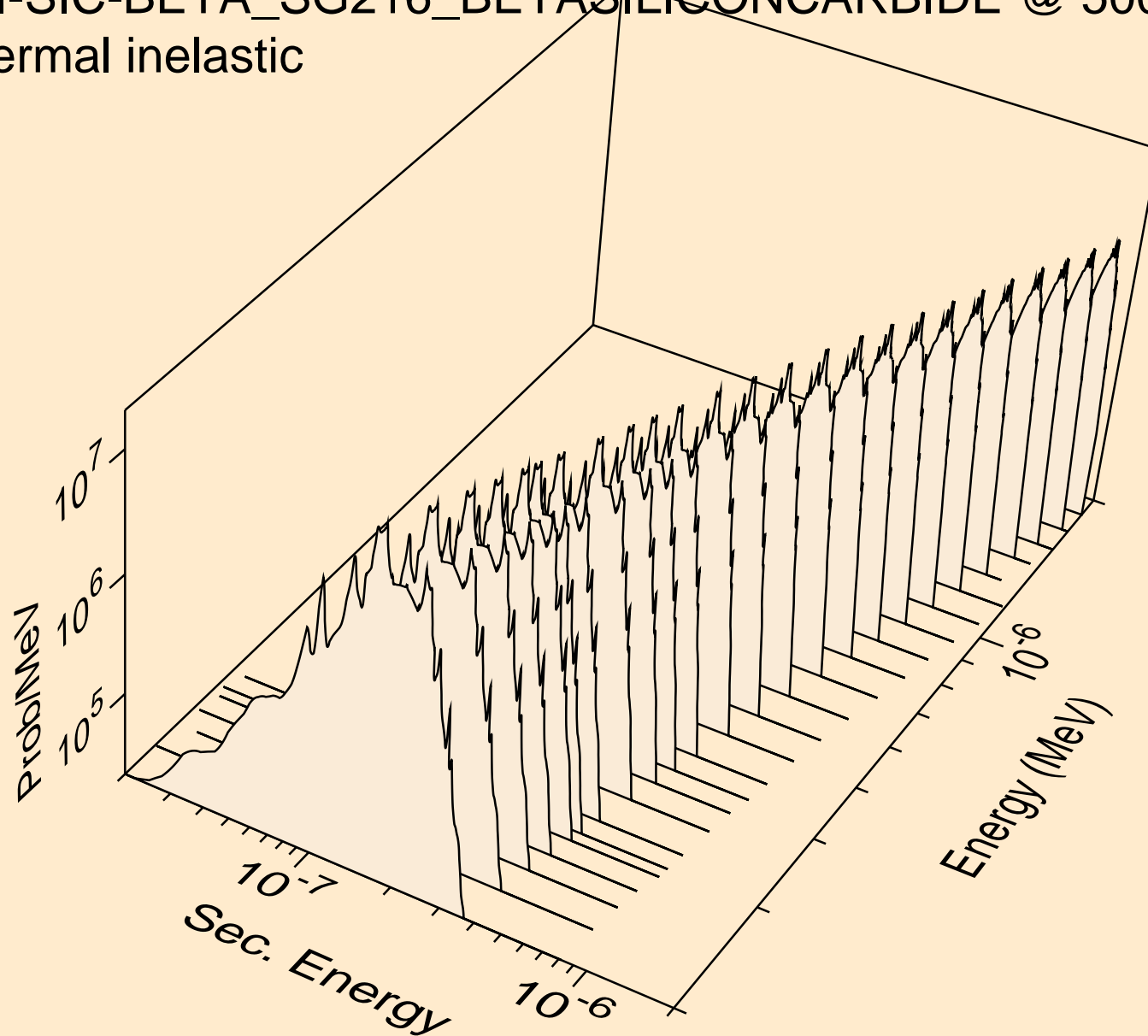
SI-SIC-BETA_SG216_BETA_SILICON CARBIDE @ 500.00K
thermal inelastic



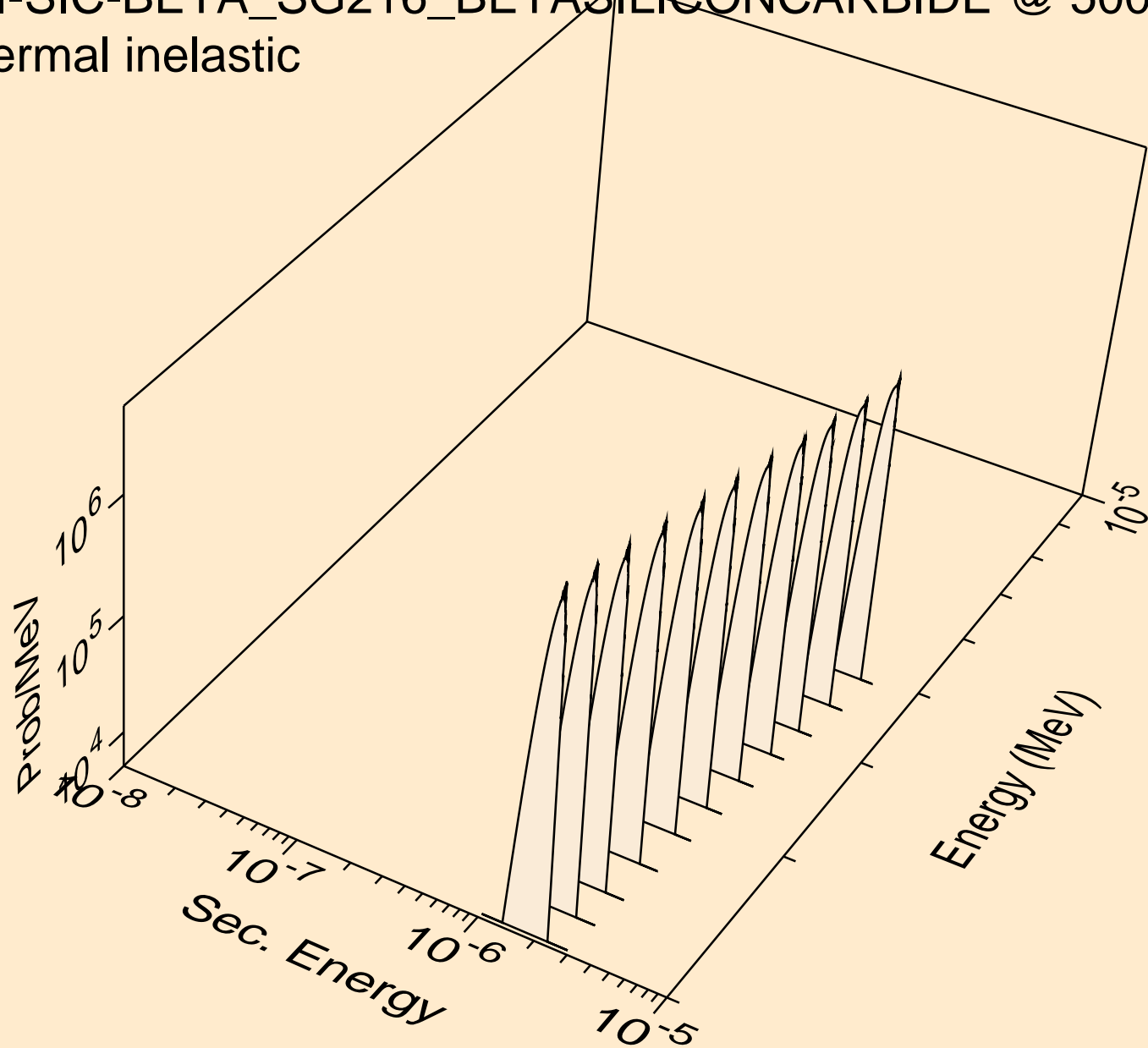
SI-SIC-BETA_SG216_BETA
SILICON CARBIDE @ 500.00K
thermal inelastic



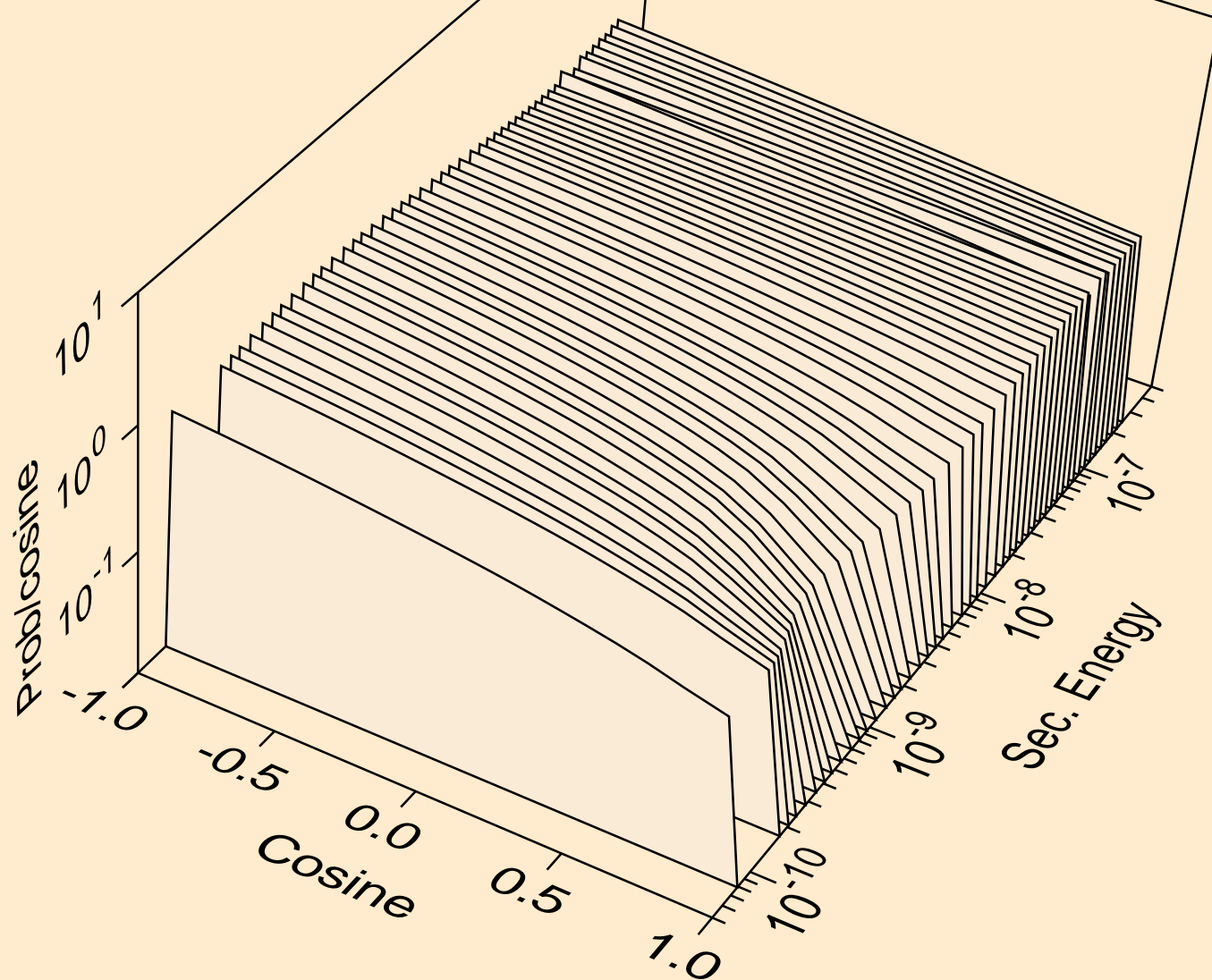
SI-SIC-BETA_SG216_BETA_SILICONCARBIDE @ 500.00K
thermal inelastic



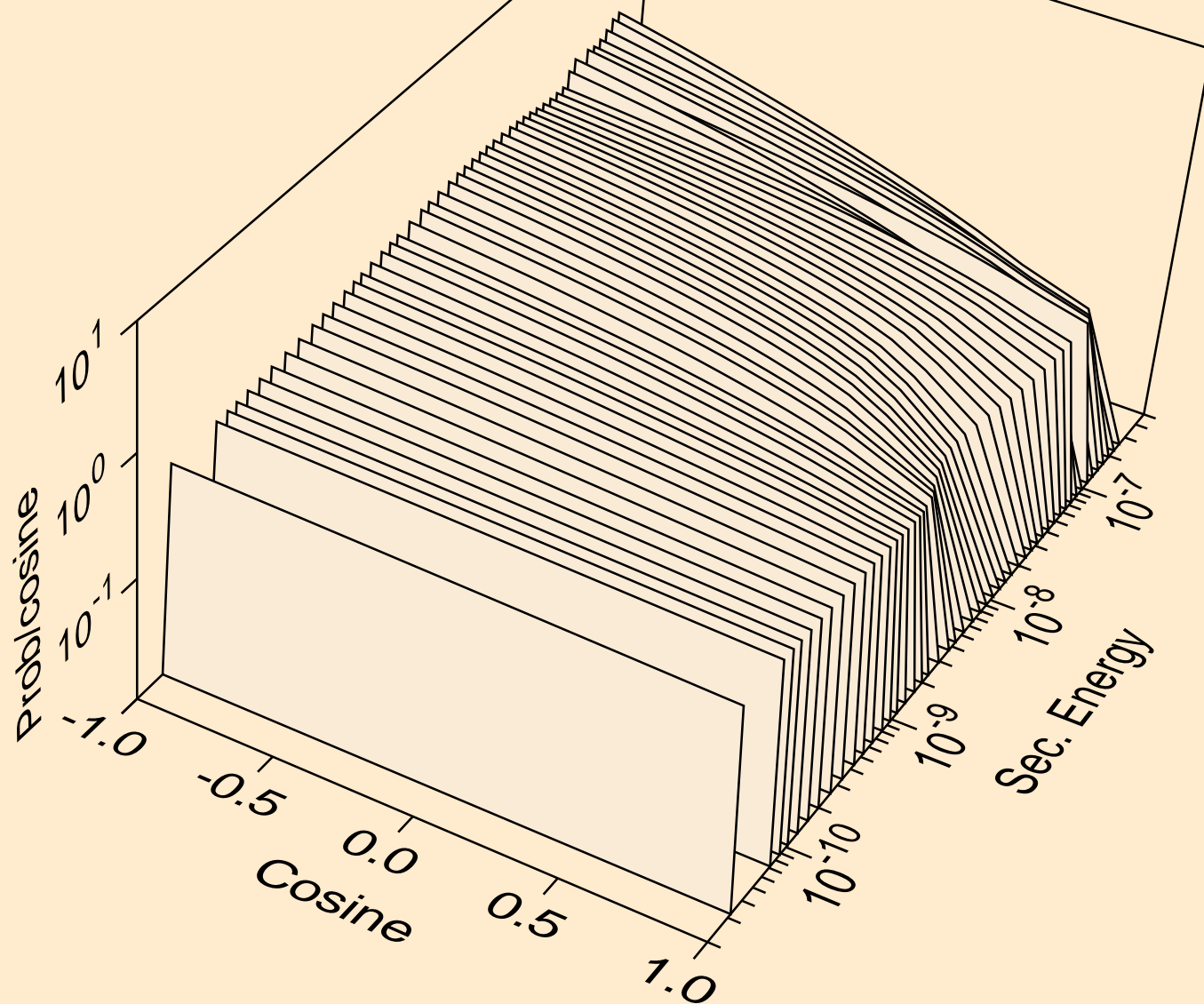
SI-SIC-BETA_SG216_BETA_SILICON CARBIDE @ 500.00K
thermal inelastic



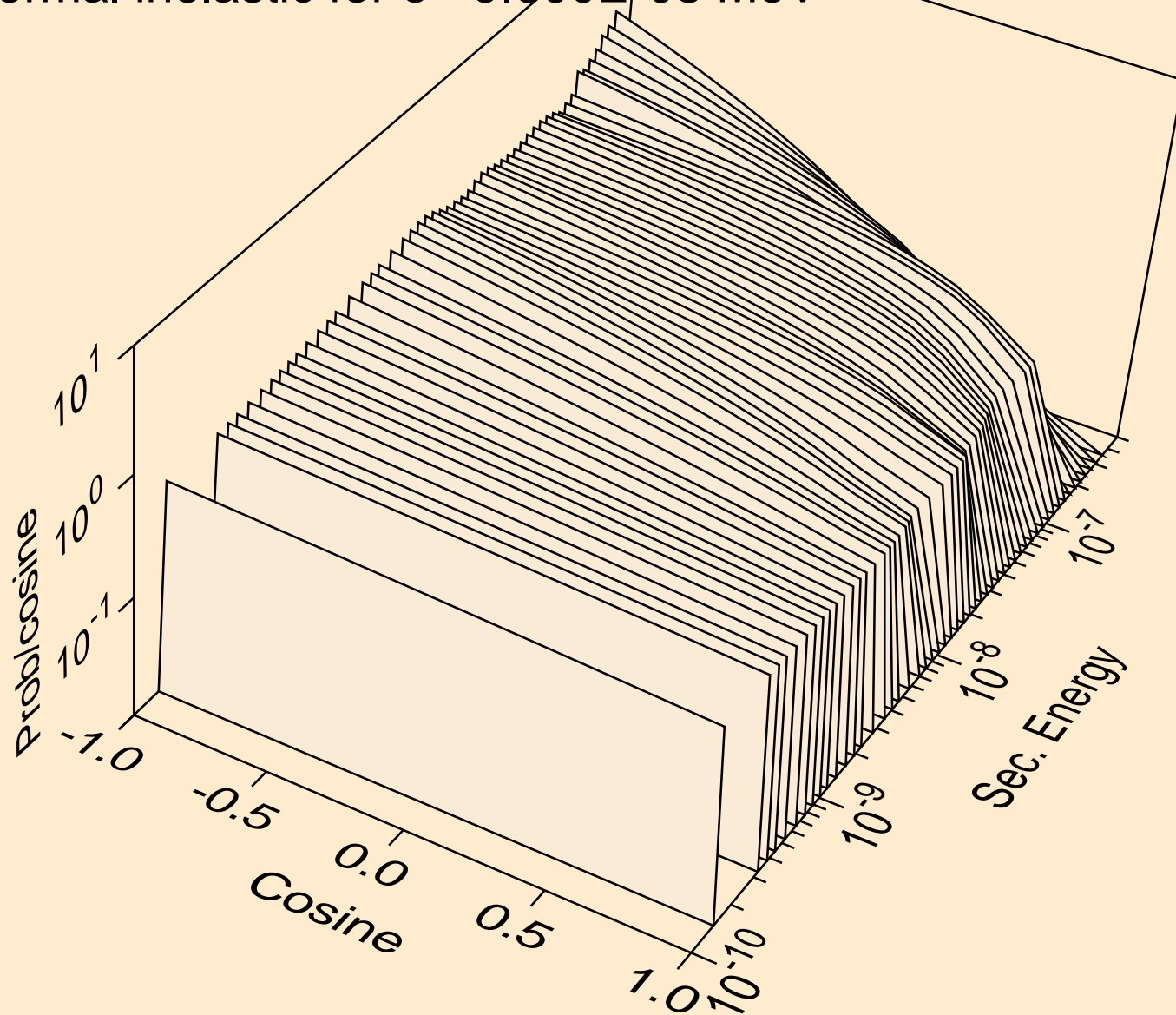
SI-SIC-BETA_SG216_BETA-SILICON CARBIDE @ 500.00K
thermal inelastic for $e = 1.012 \times 10^{-9}$ MeV



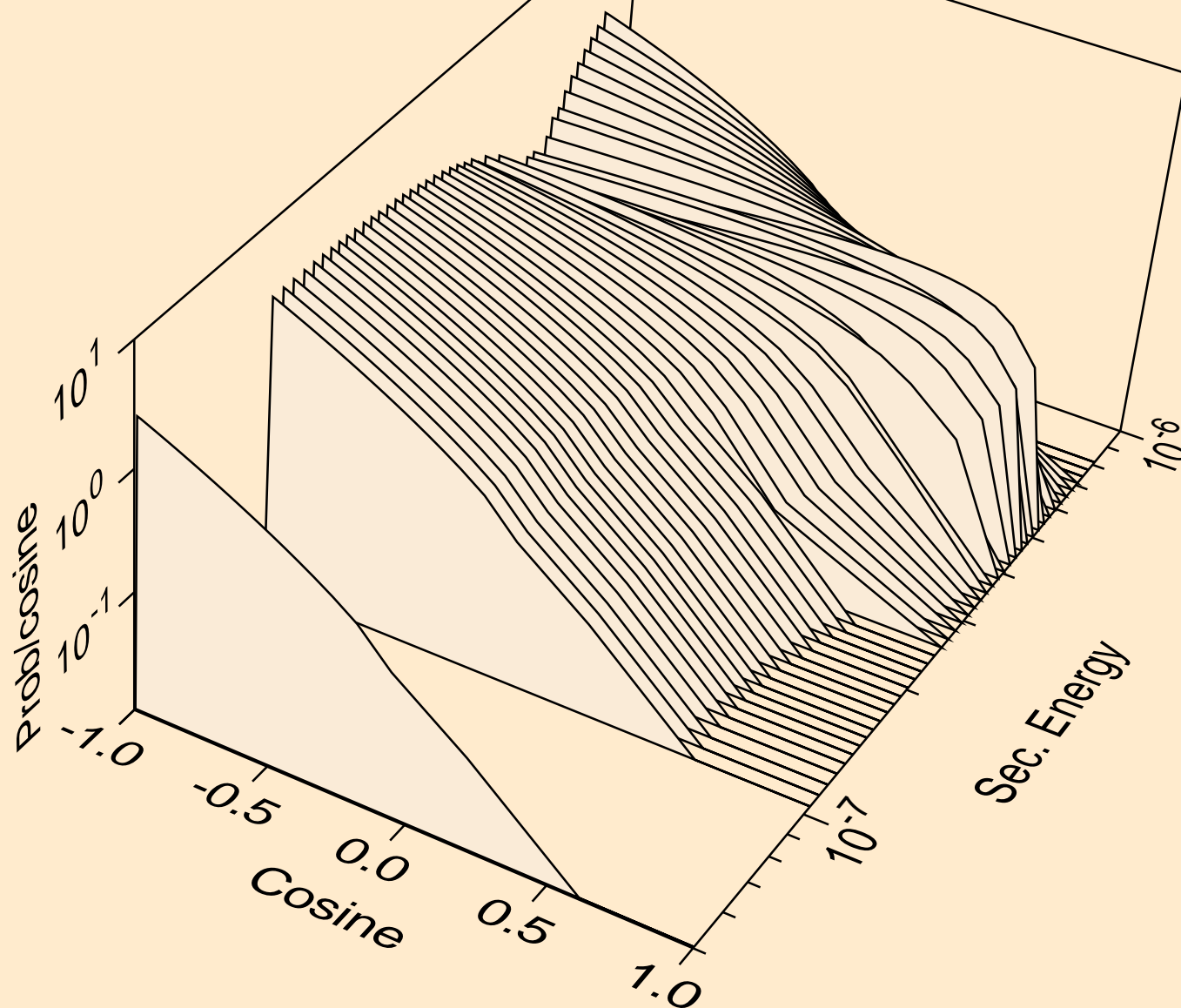
SI-SIC-BETA_SG216_BETA_SILICONCARBIDE @ 500.00K
thermal inelastic for e= 1.417E-08 MeV



SI-SIC-BETA_SG216_BETA_SILICONCARBIDE @ 500.00K
thermal inelastic for e= 9.000E-08 MeV



SI-SIC-BETA_SG216_BETA_SILICON CARBIDE @ 500.00K
thermal inelastic for $e = 5.033\text{E-}07$ MeV



SI-SIC-BETA_SG216_BETA_SILICON CARBIDE @ 500.00K
thermal inelastic for e= 4.070E-06 MeV

